

## 2N5961



### NPN General Purpose Amplifier

This device is designed for use as low noise, high gain, general purpose amplifiers requiring collector currents to 50 mA. Sourced from Process 07. See 2N5088 for characteristics.

#### Absolute Maximum Ratings\*

TA = 25°C unless otherwise noted

| Symbol                            | Parameter  | Val60ue     | Units |
|-----------------------------------|--|-------------|-------|
| V <sub>CEO</sub>                  | Collector-Emitter Voltage                        | 60          | V     |
| V <sub>CB0</sub>                  | Collector-Base Voltage                           | 60          | V     |
| V <sub>EBO</sub>                  | Emitter-Base Voltage                             | 8.0         | V     |
| I <sub>C</sub>                    | Collector Current - Continuous                   | 100         | mA    |
| T <sub>J</sub> , T <sub>stg</sub> | Operating and Storage Junction Temperature Range | -55 to +150 | °C    |

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

#### Thermal Characteristics

TA = 25°C unless otherwise noted

| Symbol           | Characteristic                                | Max    | Units |
|------------------|---|--------|-------|
|                  |   | 2N5961 |       |
| P <sub>D</sub>   | Total Device Dissipation<br>Derate above 25°C | 625    | mW    |
|                  |   | 5.0    | mW/°C |
| R <sub>θJC</sub> | Thermal Resistance, Junction to Case          | 83.3   | °C/W  |
| R <sub>θJA</sub> | Thermal Resistance, Junction to Ambient       | 200    | °C/W  |

# NPN General Purpose Amplifier

(continued)

2N5961

## Electrical Characteristics

TA = 25°C unless otherwise noted

| Symbol | Parameter | Test Conditions | Min | Max | Units |
|--------|-----------|-----------------|-----|-----|-------|
|--------|-----------|-----------------|-----|-----|-------|

### OFF CHARACTERISTICS

|               |                                      |   |     |           |          |
|---------------|--------------------------------------|---|-----|-----------|----------|
| $V_{(BR)CEO}$ | Collector-Emitter Breakdown Voltage* | $I_C = 5.0 \text{ mA}, I_B = 0$   | 60  |           | V        |
| $V_{(BR)CBO}$ | Collector-Base Breakdown Voltage     | $I_C = 10 \text{ } \mu\text{A}, I_E = 0$  | 60  |           | V        |
| $V_{(BR)EBO}$ | Emitter-Base Breakdown Voltage       | $I_E = 10 \text{ } \mu\text{A}, I_C = 0$  | 8.0 |           | V        |
| $I_{CBO}$     | Collector Cutoff Current             | $V_{CB} = 45 \text{ V}, I_E = 0$<br>$V_{CB} = 45 \text{ V}, I_E = 0, T_A = 65 \text{ }^\circ\text{C}$ |     | 2.0<br>50 | nA<br>nA |
| $I_{EBO}$     | Emitter Cutoff Current               | $V_{EB} = 5.0 \text{ V}, I_C = 0$   |     | 1.0       | nA       |

### ON CHARACTERISTICS\*

|               |                                      |  |                          |            |        |
|---------------|--------------------------------------|--|--------------------------|------------|--------|
| $h_{FE}$      | DC Current Gain                      | $V_{CE} = 5.0 \text{ V}, I_C = 10 \text{ } \mu\text{A}$<br>$V_{CE} = 5.0 \text{ V}, I_C = 100 \text{ } \mu\text{A}$<br>$V_{CE} = 5.0 \text{ V}, I_C = 1.0 \text{ mA}$<br>$V_{CE} = 5.0 \text{ V}, I_C = 10 \text{ mA}$ | 100<br>120<br>135<br>150 | 700        |        |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$<br>$I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$   |                          | 0.2<br>0.2 | V<br>V |
| $V_{BE(on)}$  | Base-Emitter On Voltage              | $V_{CE} = 5.0 \text{ V}, I_C = 1.0 \text{ mA}$   | 0.5                      | 0.7        | V      |

### SMALL SIGNAL CHARACTERISTICS

|          |                            |   |            |                   |                |
|----------|----------------------------|---|------------|-------------------|----------------|
| $C_{cb}$ | Collector-Base Capacitance | $V_{CB} = 5.0 \text{ V}, f = 1.0 \text{ MHz}$   |            | 4.0               | pF             |
| $C_{eb}$ | Emitter-Base Capacitance   | $V_{EB} = 0.5 \text{ V}, f = 1.0 \text{ MHz}$   |            | 6.0               | pF             |
| $h_{fe}$ | Small-Signal Current Gain  | $I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V},$<br>$f = 1.0 \text{ kHz}$<br>$I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V},$<br>$f = 100 \text{ MHz}$  | 150<br>1.0 | 1000              |                |
| NF       | Noise Figure               | $V_{CE} = 5.0 \text{ V}, I_C = 10 \text{ } \mu\text{A},$<br>$R_S = 10 \text{ k}\Omega, f = 1.0 \text{ kHz},$<br>$B_W = 400 \text{ Hz}$<br>$V_{CE} = 5.0 \text{ V}, I_C = 10 \text{ } \mu\text{A},$<br>$R_S = 10 \text{ k}\Omega, f = 10 \text{ Hz} - 10 \text{ kHz}$<br>$B_W = 15.7 \text{ kHz}$<br>$V_{CE} = 5.0 \text{ V}, I_C = 100 \text{ } \mu\text{A},$<br>$R_S = 1.0 \text{ k}\Omega, f = 1.0 \text{ kHz}$<br>$B_W = 400 \text{ Hz}$ |            | 3.0<br>3.0<br>6.0 | dB<br>dB<br>dB |

\*Pulse Test: Pulse Width  $\leq 300 \text{ } \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$